NSN 5961-01-042-9367

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Diode Semiconductor Device - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5961-01-042-9367	
Inclosure Material:	
Glass	
Overall Length:	
Between 0.230 inches and 0.300 inches	
Terminal Length:	
Between 1.000 inches and 1.500 inches	
Overall Diameter:	
Between 0.092 inches and 0.130 inches	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
17.0 regulator voltage	
Current Rating Per Characteristic:	
700.00 milliamperes forward current, average pascal	
Power Rating Per Characteristic:	
400.0 milliwatts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specif	cation
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain	า
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/437 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiia:	